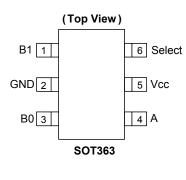
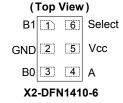


Description

The 74LVC1G3157 is a single-pole, double-throw analog switch. The device is designed for operation with a power supply range of 1.65V to 5.5V. The bidirectional switch can handle signal amplitudes between Vcc and Ground. The OFF state impedance of the switch is typically $50M\Omega$ while the ON state is typically 6Ω .

Pin Assignments





Packages not to scale

Features

- Wide Supply Voltage Range from 1.65 to 5.5V
- Control Pin Includes Hysteresis Allowing for Slower Input Rise and Fall Times
- CMOS Low Power Consumption
- Very Low ON-State Resistance
- 7.5 Ω (typical) at V_{CC} = 2.7V
- 6.5Ω (typical) at V_{CC} = 3.3V
- 6Ω (typical) at V_{CC} = 4.5V
- Break Before Make Switching
- Control Input accepts up to 5.5V Regardless of Vcc.
- Direct Interface with TTL Levels when $V_{CC} = 3.3V$
- ESD Protection Tested per JESD 22
- Exceeds 2,000-V Human Body Model (A114)
- Exceeds 1,000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Range of Package Options
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact</u> <u>us</u> or your local Diodes representative.

https://www.diodes.com/guality/product-definitions/

Notes:

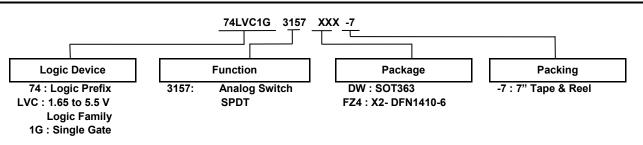
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Applications

- Multiplexing of Analog Signals
- Multiplexing of Digital Signals
- Wide array of products such as:
 - Tablets, E-readers, Wearables
 - Cell Phones, Personal Navigation / GPS
 - MP3 Players, Cameras, Video Recorders
 - Computer Peripherals, Hard Drives, CD/DVD ROMs
 - TV, DVD, DVR, Set Top Boxes
 - PCs, Networking, Notebooks, Netbooks, PDAs



Ordering Information (Note 4)



| Device | Package | Package | Package | 7" Tape and R | Reel (Note 6) | | |
|------------------|---------|--------------|---|-------------------|--------------------|--|--|
| Device | Code | (Note 5) | Size | Quantity | Part Number Suffix | | |
| 74LVC1G3157DW-7 | DW | SOT363 | 2.0mm x 2.0mm x 1.1mm 0.65 mm lead pitch | 3,000/Tape & Reel | -7 | | |
| 74LVC1G3157FZ4-7 | FZ4 | X2-DFN1410-6 | 1.4mm x 1.0mm x 0.4mm 0.5 mm pad pitch | 5,000/Tape & Reel | -7 | | |

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/. For a packaging detains, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Pin Descriptions

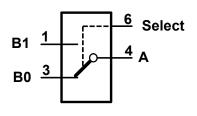
Notes:

| Pin Name | Description |
|-----------------|---------------------|
| B1 | Selectable Data I/0 |
| GND | Ground |
| B0 | Selectable Data I/0 |
| А | Common Data I/0 |
| V _{cc} | Supply Voltage |
| Select | Selection Pin |

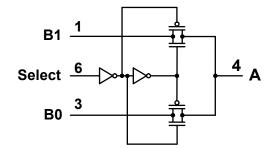
Function Table

| Select | Status |
|--------|--------------------|
| Ц | B1 connected to A; |
| п | B0 high impedance |
| | B0 connected to A; |
| L | B1 high impedance |

Logic Diagram



Simplified Schematic





Absolute Maximum Ratings (Note 7)

| Symbol | Description | Rating | Unit |
|-----------------------------------|--|------------------------------|------|
| ESD HBM | Human Body Model ESD Protection | 2 | kV |
| ESD CDM | Charged Device Model ESD Protection | 1 | kV |
| V _{cc} | Supply Voltage Range | -0.5 to 6.5 | V |
| V _{IN} | Input Voltage Range Applicable to Select Pin | -0.5 to 6.5 | V |
| V _{sw} | Voltage Range Applicable to B0, B1, and A Pins | -0.5 to V _{cc} +0.5 | V |
| I _{IK} | Input Clamp Current V _I <0 Applicable to Select Pin | -50 | mA |
| l _{io} | Continuous Current Applicable to B0,B1, and A Pins | ±50 | mA |
| I _{CC,} I _{GND} | Continuous current through V _{cc} or GND | ±100 | mA |
| TJ | Operating Junction Temperature | -40 to +150 | °C |
| T _{STG} | Storage Temperature | -65 to +150 | °C |

Note: 7. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions

| Symbol | | Min | Мах | Unit | |
|-----------------|-----------------------------------|--------------------------------|-----------------|------|------|
| V _{cc} | Operating Voltage | Operating | 1.65 | 5.5 | V |
| V _{IN} | Select Input Voltage | | 0 | 5.5 | V |
| V _{sw} | Switch Voltage (applicable to pin | -0.2 | V _{cc} | V | |
| | Input Transition Rise or Fall | V _{CC} = 1.65 to 2.7V | - | 20 | |
| Δt/ΔV | Rate – Select Pin | V _{CC} = 2.7V to 5.5V | - | 10 | ns/V |
| T _A | Operating Free-Air Temperature | - | -40 | +125 | °C |



Electrical Characteristics (All typical values are at, T_J = +25°C)

| | | | | TA | = -40 to +85° | °C | T _A = -40 | to +125°C | |
|----------------------------|---|--|--------------|---------------------|---------------|---------------------|----------------------|---------------------|-----|
| Symbol Parameter | Test Condition | V _{cc} (V) | Min | Typical (Note 8) | Мах | Min | Max | Unit | |
| | | | 1.65 to 1.95 | 0.65V _{CC} | - | - | $0.65V_{CC}$ | - | |
| M | High Level | | 2.3 to 2.7 | 1.7 | - | - | 1.7 | - | v |
| VIH | V _{IH} Input Voltage Select Pin | - | 3 to 3.6 | 2.0 | - | - | 2.0 | - | 7 V |
| | | | 4.5 to 5.5 | 0.7V _{CC} | - | - | $0.7V_{CC}$ | - | 1 |
| | | | 1.65 to 1.95 | - | - | 0.35V _{CC} | - | 0.35V _{cc} | 1 |
| N/ | Low Level | | 2.3 to 2.7 | - | - | 0.7 | - | 0.7 | |
| V _{IL} | Input Voltage Select Pin | - | 3 to 3.6 | - | - | 0.8 | - | 0.8 | V |
| | | | 4.5 to 5.5 | - | - | 0.3V _{CC} | - | 0.3V _{CC} | 1 |
| I _{IN} | Input Leakage Current Select Pin | 0 ≤ Select ≤ 5.5V | 0 to 5.5 | - | ±0.05 | ±1 | - | ±10 | μA |
| $I_{S(OFF)}$ | OFF State Leakage Current | 0V ≤ A, B _n ≤ V _{CC} Figure 1 | 1.65 to 5.5 | - | ±0.05 | ±1 | - | ±10 | μA |
| I _{S(ON)} | ON State Leakage Current | $0V \le A, B_n \le V_{CC}$ Figure 2 | 1.65 to 5.5 | - | ±0.05 | ±1 | - | ±10 | μA |
| I _{S(ON)} | ON State Leakage Current | -0.1V \leq A, B _n \leq V _{CC} Figure 2 | 1.65 to 5.5 | - | ±0.05 | ±2 | - | ±20 | μA |
| I _{CC} | Quiescent Supply Current | Select = V_{CC} or GND A, Bn = V_{CC} or GND I_{OUT} = 0 | 5.5 | - | 1.0 | 10 | - | 40 | μA |
| Δl _{cc} | Additional Supply Current | Select= $V_{CC} - 0.6V$ A, B _n = V_{CC} or GND $I_{OUT} = 0$ | 5.5 | - | 30 | 500 | - | 5,000 | μA |
| Cı | Input Capacitance Select Pin | - | 3.3 | - | 2.5 | - | - | - | pF |
| $C_{\text{S}(\text{OFF})}$ | OFF State Capacitance | Select = V_{CC} or GND A, B _n = V_{CC} or GND I_{OUT} = 0 | 3.3 | - | 6.0 | - | - | - | pF |
| $C_{S(ON)}$ | ON State Capacitance | Select = V_{CC} or GND A, B _n = V_{CC} or GND I_{OUT} = 0 | 3.3 | - | 18 | - | - | - | pF |

Note: 8. Typical performance information is included in figures 11 to 34 on pages 11 to 14.



| | | Test Condition | | T₄ | , = -40 to +85° | °C | T _A = -40 | to +125°C | |
|------------------------|---------------------------|--|---------------------|------|-----------------|-----|----------------------|-----------|------|
| Symbol | Parameter | (Note 9) | V _{cc} (V) | Min | Тур | Max | Min | Max | Unit |
| | $V_1 = 0V, I_0 = 4mA$ | 4.05 | - | 12.5 | 18 | - | 27 | | |
| | | V _I = 1.65V, I _O = -4mA | 1.65 | - | 14 | 18 | - | 35 | |
| | $V_1 = 0V, I_0 = 8mA$ | 0.0 | - | 9.0 | 16 | - | 24 | | |
| | | V _I = 2.3V, I _O =-8mA | 2.3 | - | 9.0 | 16 | - | 30 | |
| | | V _I = 0V, I _O = 12mA | 0.7 | - | 8.0 | 14 | - | 21 | |
| R _{on} | ON Resistance | V ₁ = 2.7V, I ₀ =-12mA | 2.7 | - | 8.0 | 14 | - | 27 | Ω |
| | | V ₁ = 0V, I ₀ = 24mA | | - | 7.0 | 12 | - | 18 | |
| | | V _I = 3.0V, I _O =-24mA | 3.0 | - | 7.0 | 12 | - | 23 | |
| | | V _I = 0V, I _O = 32mA | | - | 5.5 | 10 | - | 15 | |
| | | V ₁ = 2.7V, I ₀ =-32mA | 4.5 | - | 6.0 | 12 | - | 17 | - |
| | | V _I = 4.5V, I _O =-32mA | | - | 5.5 | 10 | - | 15 | |
| | | $I_A = 4mA, 0 \le V_{BN} \le V_{CC}$ | 1.65 | - | 34 | 130 | - | 195 | Ω |
| | On | $I_A = 8mA, 0 \le V_{BN} \le V_{CC}$ | 2.3 | - | 5 | 30 | - | 45 | |
| R _{RANGE} | Resistance Over Signal | $I_A = 12mA, 0 \le V_{BN} \le V_{CC}$ | 2.7 | - | 4 | 25 | - | 38 | |
| | Range | $I_A = 24mA, 0 \le V_{BN} \le V_{CC}$ | 3.0 | - | 7.8 | 20 | - | 30 | |
| | | $I_A = 32mA, 0 \le V_{BN} \le V_{CC}$ | 4.5 | - | 6.2 | 15 | - | 23 | |
| | | I _A = -4mA, V _{BN} = 1.15 V | 1.65 | - | 0.25 | - | - | - | |
| | On Resistance | I _A = -8mA, V _{BN} = 1.6 V | 2.3 | - | 0.25 | - | - | - | |
| ΔR_{ON} | Match Between | $I_A = -12mA,$ $V_{BN} = 1.9 V$ | 2.7 | - | 0.25 | - | - | - | Ω |
| | Channels (Note 10) | $I_{A} = -24mA,$ $V_{BN} = 2.1$ | 3.0 | - | 0.25 | - | - | - | - |
| | | I _A = -32mA, V _{BN} = 3.15 | 4.5 | - | 025 | - | - | - | |
| | | $I_A = -4mA, 0 \le V_{BN} \le V_{CC}$ | 1.65 | - | 26 | 110 | - | 150 | |
| | On | $I_A = -8mA, 0 \le V_{BN} \le V_{CC}$ | 2.3 | - | 5.0 | 26 | - | 105 | 1 |
| R _{flat} | Resistance Flatness | $I_{A} = -24 \text{mA}, \ 0 \le V_{BN} \le V_{CC}$ 2.7 | - | 3.5 | 16 | - | 35 | Ω | |
| | (Note 11) | $I_A = -24mA, 0 \le V_{BN} \le V_{CC}$ | 3.3 | - | 2.0 | 9 | - | 15 | |
| | | I_A = -32mA, 0 ≤ V_{BN} ≤ V_{CC} | 5.0 | - | 1.5 | 4 | - | 8 | 1 |

Electrical Characteristics (All typical values are at T₁ = +25°C)

Note:

9. Switch resistance test is measured per Figure 3. 10. ΔR_{ON} is measured at identical V_{CC}, temperature and voltage levels. 11. Flatness is defined as the difference between the maximum and minimum of ON resistance measured at identical V_{CC} and temperature.



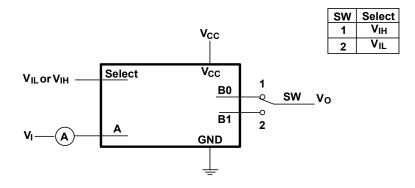
Switching Characteristics

| Symbol | Parameter | Test Condition | V _{cc} | T _A = | = -40 to + | -85°C | | -40 to 25°C | Unit | Figure |
|--------------------------------------|---|--|-----------------|------------------|------------|-------|-----|----------------|------|-----------|
| Symbol | Farameter | Test condition | Volts | Min | Тур | Мах | Min | Мах | Onit | Number |
| | _ Propagation | | 1.65 to 1.95 | - | - | 2.0 | - | 3.0 | | |
| | | | 2.3 to 2.7 | - | - | 1.2 | - | 2.0 | 1 | |
| t _{PHL} t _{PLH} | Delay | V ₁ = OPEN (Note 12) | 2.7 | - | - | 1.0 | - | 1.5 | ns | Figure 4 |
| | A to B _n | | 3.0 to 3.6 | - | - | 0.8 | - | 1.5 | | |
| | | | 4.5 to 5.5 | - | - | 0.6 | - | 1.0 | | |
| | | | 1.65 to 1.95 | 1.0 | 8.7 | 14.0 | 1.0 | 14.0 | | |
| | Output | V_{I} = 2 x V_{CC} for t_{PZL} | 2.3 to 2.7 | 1.0 | 5.3 | 7.5 | 1.0 | 7.5 | | |
| t _{PZL} t _{PZH} | Enable Time | $V_I = 0V$ for t_{PZH} | 2.7 | 1.0 | 4.9 | 6.0 | 1.0 | 6.0 | ns | Figure 4 |
| | Switch to Bn | (Note 13) | 3.0 to 3.6 | 0.5 | 4.0 | 5.5 | 0.5 | 5.5 | | |
| | | | 4.5 to 5.5 | 0.5 | 3.0 | 4.0 | 0.5 | 4.0 | | |
| | . Output V | $V_{I} = 2 \times V_{CC} \text{ for } t_{PLZ}$ $V_{I} = 0V \text{ for } t_{PHZ}$ (Note 13) | 1.65 to 1.95 | 2.5 | 6.0 | 8.5 | 2.5 | 8.5 | | Figure 4 |
| | | | 2.3 to 2.7 | 2.0 | 4.4 | 8.2 | 2.0 | 8.2 | | |
| t _{PLZ} t _{PHZ} | Disable Time | | 2.7 | 1.5 | 4.2 | 8.0 | 1.5 | 8.0 | ns | |
| | t _{PHZ} Switch to B _n | | 3.0 to 3.6 | 1.5 | 3.6 | 7.8 | 1.5 | 7.8 | | |
| | | | 4.5 to 5.5 | 0.8 | 2.9 | 7.5 | 0.8 | 7.5 | | |
| | | | 1.65 to 1.95 | 0.5 | - | | 0.5 | - | | |
| | Break Before | | 2.3 to 2.7 | 0.5 | - | - | 0.5 | - | | |
| t _{B-M} | Make Time | - | 2.7 | 0.5 | - | - | 0.5 | - | ns | Figure 5 |
| | (Note 9) | | 3.0 to 3.6 | 0.5 | | - | 0.5 | - | | |
| | | | 4.5 to 5.5 | 0.5 | - | - | 0.5 | | ns | |
| 0 | Charge | $C_L = 0.1 \text{ nF},$ $V_{GEN} = 0V$ | 5.0 | - | 7.0 | - | - | - | -0 | Figure C |
| Q | Injection (Note 9) | $R_{GEN} = 0 \Omega$ | 3.3 | | 3.0 | - | - | - | рС | Figure 6 |
| QIRR | Off Isolation (Note 11) | $R_L = 50 \Omega$, f = 10MHz | 1.65 ~ 5.5 | - | -42 | - | - | - | dB | Figure 7 |
| Xtalk | Crosstalk | $R_L = 50 \Omega$, f = 10MHz | 1.65 ~ 5.5 | - | -42 | - | - | - | dB | Figure 8 |
| BW | -3dB Bandwidth | R _L = 50 Ω | 1.65 ~ 5.5 | - | 300 | - | - | - | MHz | Figure 9 |
| THD | Total Harmonic Distortion (Note 9) | R_L = 600 Ω, 0.5 V _{P-P} , f = 600Hz to 20kHz | 5.0 | - | 0.1 | - | - | - | % | Figure 10 |

 Due to the symmetry of the part, the direction of the propagation delay applies to either direction A to B_n or B_n to A. Propagation time is the calculated RC time constant of the typical ON resistance of the switch and the specified load capacitance when capacitance when driven by an ideal voltage source.
The Switch signal enable and disables time are the same for Bn and A if they are reversed at input and output. Notes:



Parameter Measurement Information



Condition 1: $V_I = GND, V_O = V_{CC}$ Condition 2: $V_I = V_{CC}, V_O = GND$



Figure 1 OFF –State Leakage Curent Test

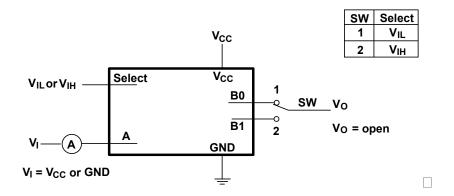


Figure 2 ON –State Leakage Curent Test

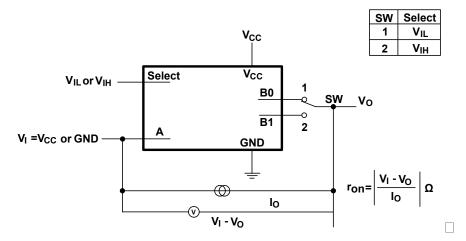
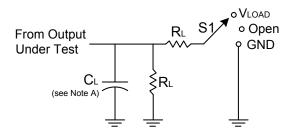


Figure 3 ON State Resistance Test

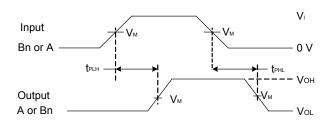


Parameter Measurement Information (Notes 15-19)

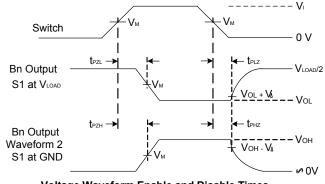


| TEST | S1 | RL |
|------------------------------------|-------|------|
| t _{PLH} /t _{PHL} | Open | 500Ω |
| t _{PLZ} /t _{PZL} | Vload | 500Ω |
| t _{PHZ} /t _{PZH} | GND | 500Ω |

| V | Inputs | | N/ | N | CL | VΔ | |
|--------------|-----------------|--------------------------------|--------------------|-------------------|-----------|------|--|
| Vcc | VI | t _r /t _f | VM | VLOAD | (Note 14) | VΔ | |
| 1.8V ± 0.15V | V _{CC} | ≤2ns | V _{CC} /2 | $2 \times V_{CC}$ | 50pF | 0.1V | |
| 2.5V ± 0.2V | V _{CC} | ≤2ns | V _{CC} /2 | $2 \times V_{CC}$ | 50pF | 0.1V | |
| 3.3V ± 0.3V | V _{CC} | ≤2.5ns | V _{CC} /2 | $2 \times V_{CC}$ | 50pF | 0.1V | |
| 5V ± 0.5V | V _{CC} | ≤2.5ns | V _{CC} /2 | $2 \times V_{CC}$ | 50pF | 0.1V | |



Voltage Waveform Propagation Delay Times



Voltage Waveform Enable and Disable Times

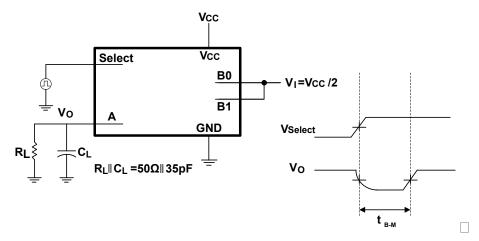
Figure 4 Load Circuit and Voltage Waveforms

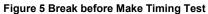
14. Includes test lead and test apparatus capacitance. Notes:

- 15. All pulses are supplied at pulse repetition rate ≤ 10MHz.
- 16. Inputs are measured separately one transition per measurement.
- 17. t_{PLZ} and t_{PHZ} are the same as $t_{dis.}$
- 18. t_{PZL} and t_{PZH} are the same as t_{EN} . 19. t_{PLH} and t_{PHL} are the same as t_{PD} .



Parameter Measurement Information (continued)





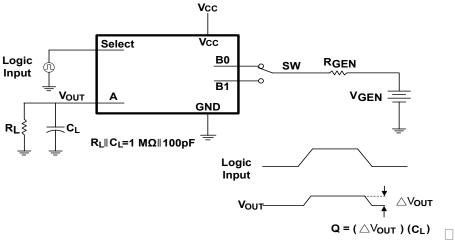
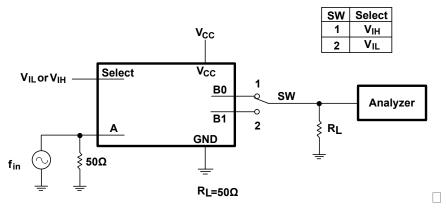


Figure 6 Charge Injection







Parameter Measurement Information (continued)

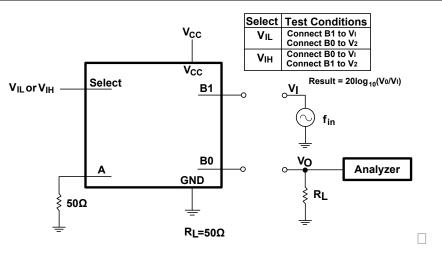
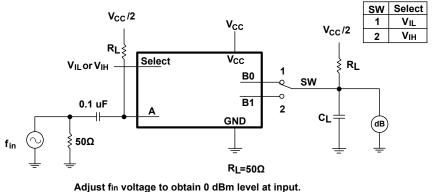
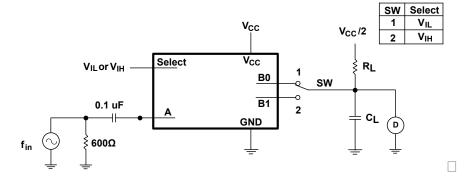


Figure 8 Cross Talk



Adjust fin voltage to obtain 0 dBm level at input. Adjust fin frequency until dB meter reads -3 dB.

Figure 9 Bandwdith

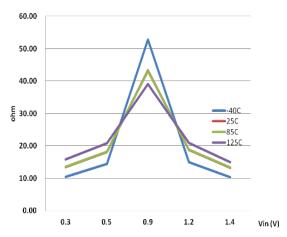




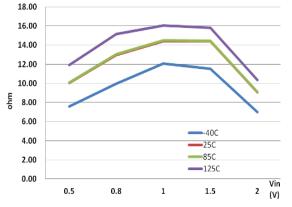
74LVC1G3157 Document number: DS38099 Rev. 4 - 2



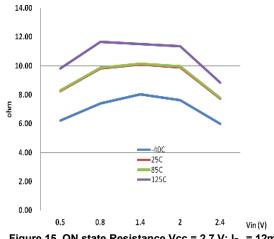
Typical Performance Characteristics



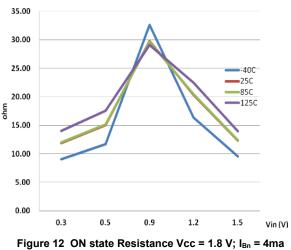


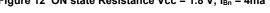


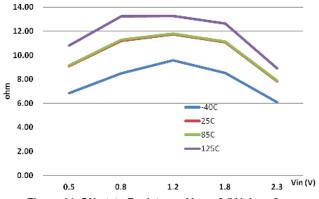




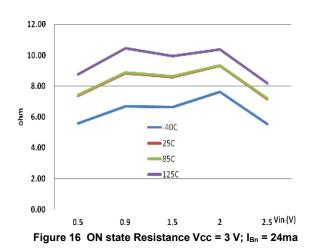














Typical Performance Characteristics (continued)

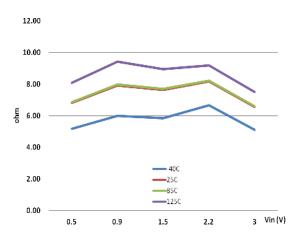


Figure 17 ON state Resistance Vcc = 3.3 V; I_{Bn} = 24ma

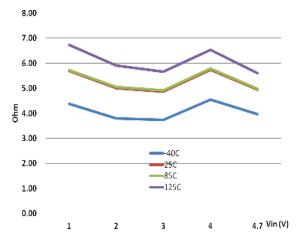
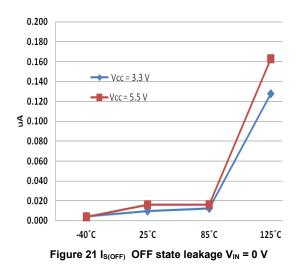
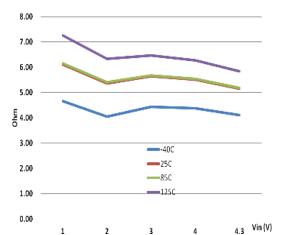


Figure 19 ON state Resistance Vcc = 5.5 V; I_{Bn} = 32ma







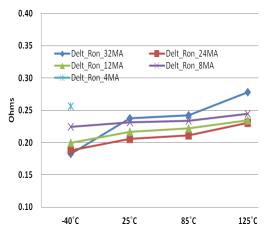


Figure 20 ARn-Resistance Match Between Channels

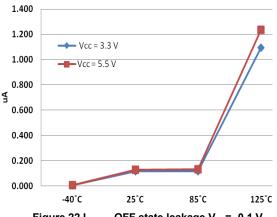
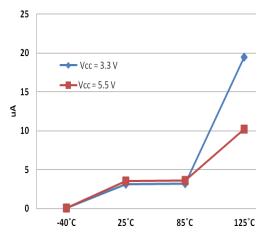


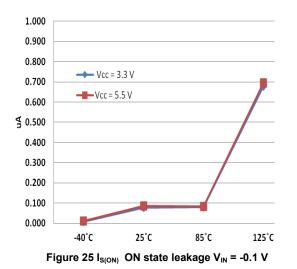
Figure 22 $I_{S(OFF)}$ OFF state leakage V_{IN} = -0.1 V

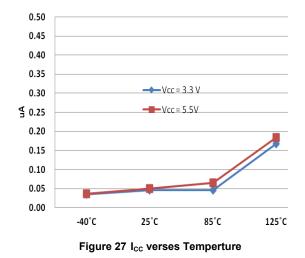


Typical Performance Characteristics (continued)









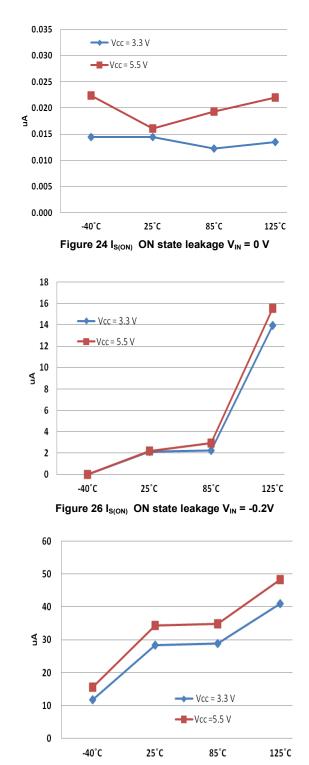
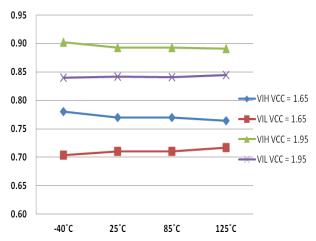


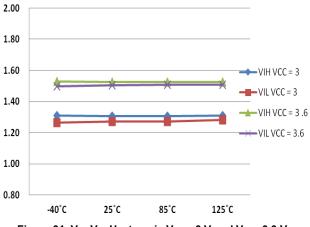
Figure 28 Delta Icc verses Temperture



Typical Performance Characteristics (continued)









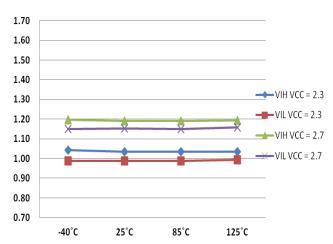


Figure 30 V_IH, VIL, Hysteresis V_{cc} = 2.3 V and V_{cc} = 2.7 V

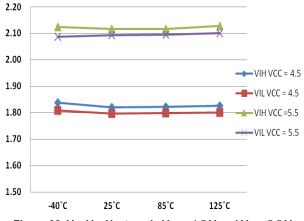
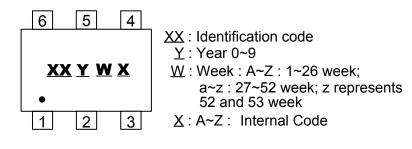


Figure 32 V_{IH}, V_{IL}, Hysteresis V_{cc} = 4.5 V and V_{cc}= 5.5 V



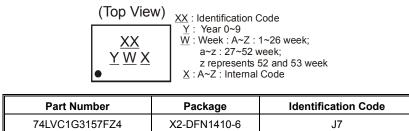
Marking Information

(1) SOT363



| Part Number | Package | Identification Code |
|---------------|---------|---------------------|
| 74LVC1G3157DW | SOT363 | J7 |

(2) X2-DFN1410-6



Package Characteristics (All typical values are at V_{CC} = 3.3V, T_A = +25°C)

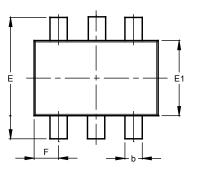
| Symbol | Parameter | Test Conditions | Vcc | Min | Тур. | Мах | Unit |
|-------------------|---------------------|-----------------|-----------|-----|------|-----|-------|
| 0 | Thermal Resistance | SOT363 | () | - | 371 | - | °0111 |
| θ_{JA} | Junction-to-Ambient | X2-DFN1410-6 | (Note 20) | - | 460 | - | °C/W |
| 0 | Thermal Resistance | SOT363 | | - | 143 | - | |
| $\theta_{\rm JC}$ | Junction-to-Case | X2-DFN1410-6 | (Note 20) | - | 265 | - | °C/W |

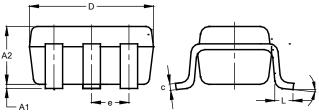
Note: 20. Test condition SOT363, and X2-DFN1410-6: Device mounted on FR-4 substrate PC board, 2oz. copper, with minimum recommended pad layout.



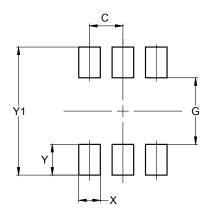
SOT363 Package Outline Dimensions and Suggested Pad Layout

 $\label{eq:plases} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$





| SOT363 | | | | | |
|----------------------|-----------|------|-------|--|--|
| Dim | Min | Max | Тур | | |
| A1 | 0.00 | 0.10 | 0.05 | | |
| A2 | 0.90 | 1.00 | 1.00 | | |
| b | 0.10 | 0.30 | 0.25 | | |
| С | 0.10 | 0.22 | 0.11 | | |
| D | 1.80 | 2.20 | 2.15 | | |
| E | 2.00 | 2.20 | 2.10 | | |
| E1 | 1.15 | 1.35 | 1.30 | | |
| е | 0.650 BSC | | | | |
| F | 0.40 | 0.45 | 0.425 | | |
| L | 0.25 | 0.40 | 0.30 | | |
| а | 0° | 8° | | | |
| All Dimensions in mm | | | | | |

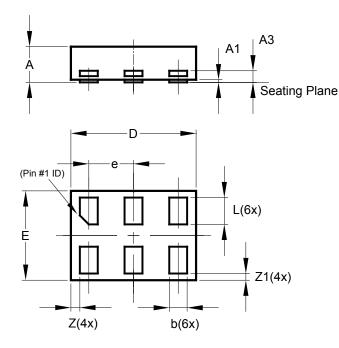


| Dimensions | Value (in mm) | |
|------------|------------------|--|
| С | 0.650 | |
| G | 1.300 | |
| Х | 0.420 | |
| Y | 0.600 | |
| Y1 | 2.500 | |

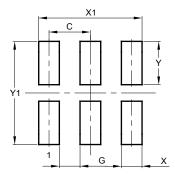


X2-DFN1410-6 Package Outline Dimensions and Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



| X2-DFN1410-6 | | | | | |
|--------------|----------------------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | - | 0.40 | 0.39 | | |
| A1 | 0.00 | 0.05 | 0.02 | | |
| A3 | _ | | 0.13 | | |
| b | 0.15 | 0.25 | 0.20 | | |
| D | 1.35 | 1.45 | 1.40 | | |
| E | 0.95 | 1.05 | 1.00 | | |
| е | | _ | 0.50 | | |
| L | 0.25 | 0.35 | 0.30 | | |
| Z | | _ | 0.10 | | |
| Z1 | 0.045 | 0.105 | 0.075 | | |
| All | All Dimensions in mm | | | | |



| Dimensions | Value (in mm) | |
|------------|------------------|--|
| C | 0.500 | |
| G | 0.250 | |
| X | 0.250 | |
| X1 | 1.250 | |
| Y | 0.525 | |
| Y1 | 1.250 | |

Mechanical Data

SOT363

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.0064 grams (Approximate)

X2-DFN1410-6

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu Nickel Palladium Gold, Solderable per MIL-STD-202, Method 208 @
- Weight: 0.002 grams (Approximate)



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